

TECHNICAL DATA DATASHEET 4792, REV.A

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 60 VOLT, 10 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGSALL RATINGS ARE @ $T_c = 25 \degree C UNL$	ALL RATINGS ARE @ $T_c = 25$ °C UNLESS OTHERWISE SPECIFIED.				
RATING	SYMBOL	MAX.	UNITS		
PEAK INVERSE VOLTAGE	PIV	60	Volts		
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ $T_c=100$ °C) (Single)	Ι _Ο	5.0	Amps		
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ $T_c=100$ °C) (Common Cathode)	Ι _Ο	10	Amps		
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	140	Amps		
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	Ст	400	pF		
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C		

ELECTRICAL CHARACTERISTICS

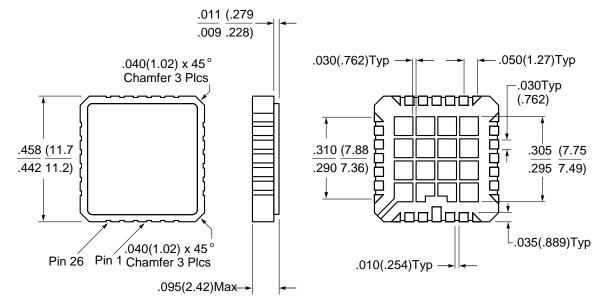
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed $(I_f = 10 \text{ Amps})$			
T _J = 25 °C	V _f	0.73	Volts
T _J = 125 °C		0.65	
MAXIMUM REVERSE CURRENT (Ir @ 60 V PIV)			
T _J = 25 °C	l _r	0.2	mA
T _J = 125 °C		15	

SENSITRON SEMICONDUCTOR

SHD130123 SHD130123P

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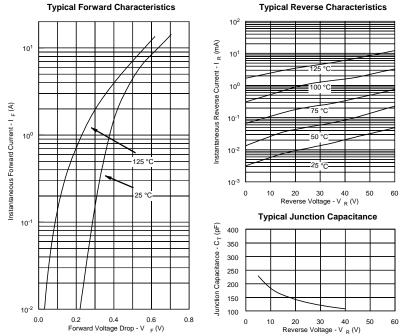
MECHANICAL DIMENSIONS: IN Inches / mm



LCC-28T

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2



SENSITRON SEMICONDUCTOR

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